

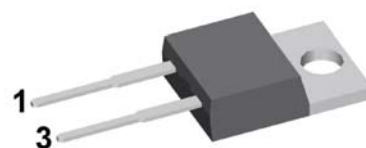
Schottky Diode Gen ²

preliminary

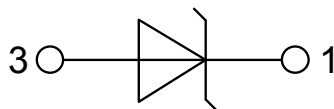
$$\begin{aligned} V_{RRM} &= 100V \\ I_{FAV} &= 30A \\ V_F &= 0.78V \end{aligned}$$

High Performance Schottky Diode
Low Loss and Soft Recovery
Single Diode

Part number

DSA30I100PA


Backside: cathode



Features / Advantages:

- Very low V_f
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

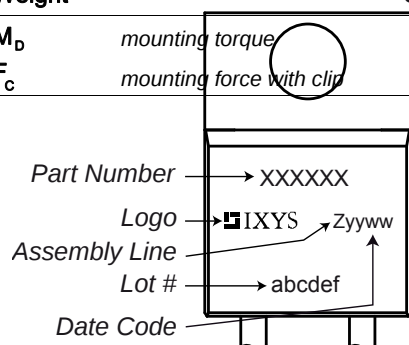
Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}\text{C}$				100	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}\text{C}$				100	V
I_R	reverse current, drain current	$V_R = 100\text{ V}$	$T_{VJ} = 25^{\circ}\text{C}$			450	μA
		$V_R = 100\text{ V}$	$T_{VJ} = 125^{\circ}\text{C}$			5	mA
V_F	forward voltage drop	$I_F = 30\text{ A}$	$T_{VJ} = 25^{\circ}\text{C}$			0.95	V
		$I_F = 60\text{ A}$				1.15	V
		$I_F = 30\text{ A}$	$T_{VJ} = 125^{\circ}\text{C}$			0.78	V
		$I_F = 60\text{ A}$				1.01	V
I_{FAV}	average forward current	$T_C = 150^{\circ}\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 175^{\circ}\text{C}$			30	A
V_{FO}	threshold voltage	} for power loss calculation only				0.46	V
r_F	slope resistance					7.8	m Ω
R_{thJC}	thermal resistance junction to case					0.85	K/W
R_{thCH}	thermal resistance case to heatsink				0.50		K/W
P_{tot}	total power dissipation	$T_C = 25^{\circ}\text{C}$				175	W
I_{FSM}	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$	$T_{VJ} = 45^{\circ}\text{C}$			440	A
C_J	junction capacitance	$V_R = 12\text{ V}$ $f = 1\text{ MHz}$	$T_{VJ} = 25^{\circ}\text{C}$		289		pF

preliminary

Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			35	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight	Product Marking			2		g
M_D	mounting torque		0.4		0.6	Nm
F_C	mounting force with clip		20		60	N

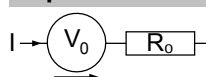


D = Diode
 S = Schottky Diode
 A = low VF
 30 = Current Rating [A]
 I = Single Diode
 100 = Reverse Voltage [V]
 PA = TO-220AC (2)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA30I100PA	DSA30I100PA	Tube	50	504162

Equivalent Circuits for Simulation

* on die level

 $T_{VJ} = 175^{\circ}\text{C}$ 

Schottky

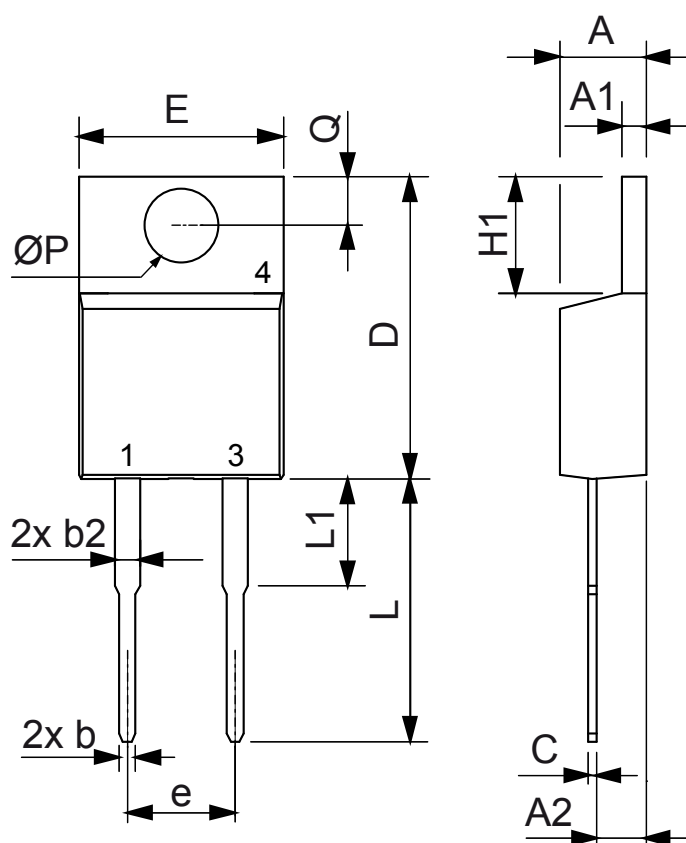
 $V_{0\max}$ threshold voltage 0.46

V

 $R_{0\max}$ slope resistance * 4.6

mΩ

Outlines TO-220



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	5.08	BSC	0.200	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
$\varnothing P$	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125

